

3.3-V CAN TRANSCEIVER

FEATURES

- Bus-Pin Fault Protection Exceeds ± 36 V
- Bus-Pin ESD Protection Exceeds 16-kV Human Body Model (HBM)
- Compatible With ISO 11898
- Signaling Rates⁽¹⁾ up to 1 Mbps
- Extended -7 -V to 12-V Common-Mode Range
- High-Input Impedance Allows for 120 Nodes
- LVTTTL I/Os Are 5-V Tolerant
- Adjustable Driver Transition Times for Improved Signal Quality
- Unpowered Node Does Not Disturb the Bus
- Low-Current Standby Mode . . . 200 μ A Typical
- Power-Up/Down Glitch-Free Bus Inputs and Outputs
 - High Input Impedance With Low V_{CC}
 - Monolithic Output During Power Cycling
- Loopback for Diagnostic Functions Available
- DeviceNet™ Vendor ID #806

⁽¹⁾ The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

APPLICATIONS

- Down-Hole Drilling
- High Temperature Environments
- Industrial Automation
 - DeviceNet™ Data Buses
 - Smart Distributed Systems (SDS™)
- SAE J1939 Data Bus Interface
- NMEA 2000 Data Bus Interface
- ISO 11783 Data Bus Interface
- CAN Data Bus Interface

SUPPORTS EXTREME TEMPERATURE APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Extreme ($-55^{\circ}\text{C}/210^{\circ}\text{C}$) Temperature Range⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- Texas Instruments high temperature products utilize highly optimized silicon (die) solutions with design and process enhancements to maximize performance over extended temperatures.

DESCRIPTION/ORDERING INFORMATION

The SN65HVD233 is used in applications employing the controller area network (CAN) serial communication physical layer in accordance with the ISO 11898 standard, with the exception that the thermal shutdown is removed. As a CAN transceiver, the device provides transmit and receive capability between the differential CAN bus and a CAN controller, with signaling rates up to 1 Mbps.

Designed for operation in especially harsh environments, the device features cross wire, overvoltage, and loss-of-ground protection to ± 36 V, with common-mode transient protection of ± 100 V. This device operates over a -7 -V to 12-V common-mode range with a maximum of 60 nodes on a bus.

If the common-mode range is restricted to the ISO 11898 standard range of -2 V to 7 V, up to 120 nodes may be connected on a bus. This transceiver interfaces the single-ended CAN controller with the differential CAN bus found in industrial, building automation, and automotive applications.

⁽¹⁾ Custom temperature ranges available

PRODUCT PREVIEW


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DeviceNet is a trademark of Open DeviceNet Vendor Association.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

R_S (pin 8) provides for three modes of operation: high-speed, slope control, or low-power standby mode. The high-speed mode of operation is selected by connecting R_S directly to ground, allowing the driver output transistors to switch on and off as fast as possible with no limitation on the rise and fall slope. The rise and fall slope can be adjusted by connecting a resistor to ground at R_S, since the slope is proportional to the pin's output current. Slope control is implemented with a resistor value of 10 kΩ to achieve a slew rate of ≈ 15 V/μs, and a value of 100 kΩ to achieve ≈ 2.0 V/μs slew rate. For more information about slope control, refer to the application information section.

The SN65HVD233 enters a low-current standby mode, during which the driver is switched off and the receiver remains active if a high logic level is applied to R_S. The local protocol controller reverses this low-current standby mode when it needs to transmit to the bus.

A logic high on the loopback (LBK, pin 5) of the SN65HVD233 places the bus output and bus input in a high-impedance state. The remaining circuit remains active and available for the driver to receiver loopback, self-diagnostic node functions without disturbing the bus.

AVAILABLE OPTIONS

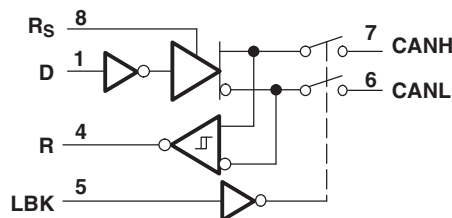
| PART NUMBER | LOW-POWER MODE | SLOPE CONTROL | DIAGNOSTIC LOOPBACK | AUTOBAUD LOOPBACK |
|-----------------|---------------------|---------------|---------------------|-------------------|
| SN65HVD233SJD | 200-μA standby mode | Adjustable | Yes | No |
| SN65HVD233SKGDA | 200-μA standby mode | Adjustable | Yes | No |

ORDERING INFORMATION⁽¹⁾

| PACKAGE (JD) ⁽²⁾ | TOP-SIDE MARKING |
|-----------------------------------|------------------|
| SN65HVD233SJD | SN65HVD233SJD |
| PACKAGE (BARE DIE) ⁽²⁾ | |
| SN65HVD233SKGDA | |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTIONAL BLOCK DIAGRAM

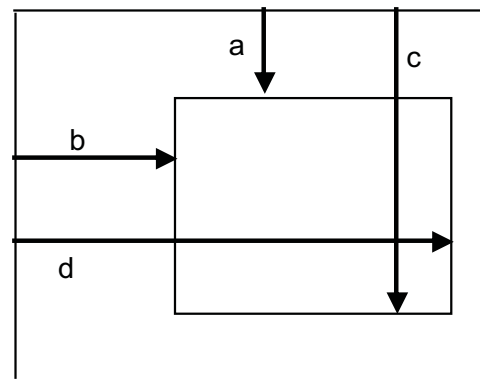


PRODUCT PREVIEW

BARE DIE INFORMATION

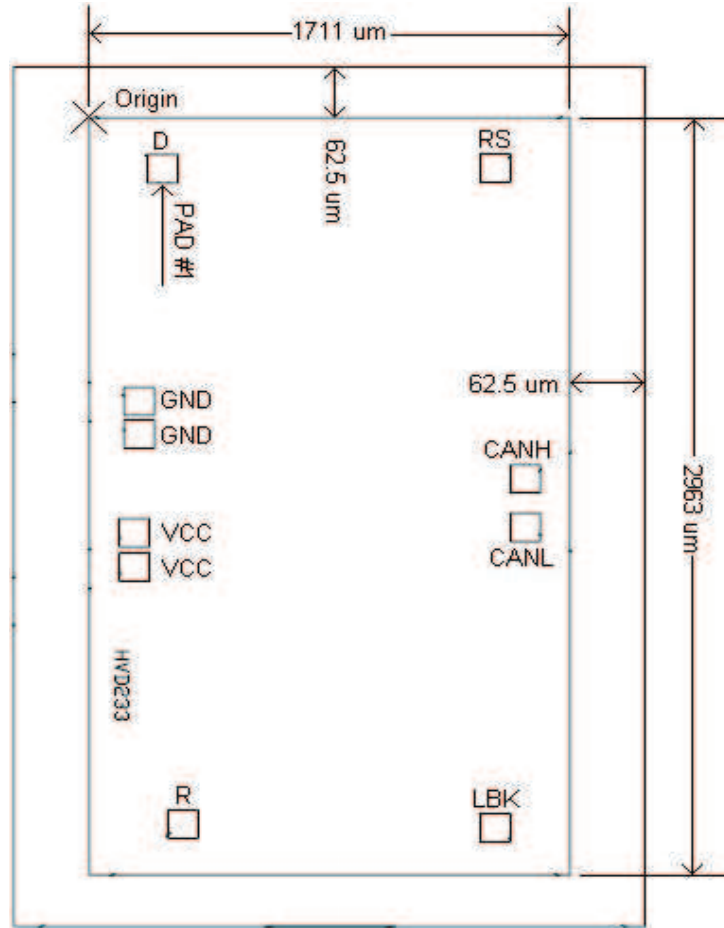
| DIE THICKNESS | BACKSIDE FINISH | BACKSIDE POTENTIAL | BOND PAD METALLIZATION COMPOSITION |
|---------------|------------------------|--------------------|------------------------------------|
| 15 mm | Silicon with backgrind | GND | Al-Si-Cu (0.5%) |

Origin


Bond Pad Coordinates in Microns - Rev A

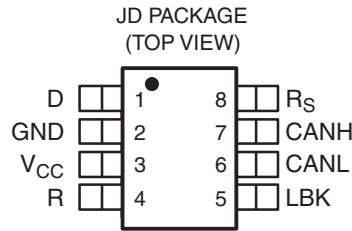
| DISCRIPTION | PAD NUMBER | a | b | c | d |
|-------------|------------|---------|----------|---------|---------|
| D | 1 | 86.40 | 157.85 | 203.40 | 274.85 |
| GND | 2 | 1035.05 | 69.75 | 1150.05 | 184.75 |
| GND | 3 | 1168.15 | 69.75 | 1283.15 | 184.75 |
| VCC | 4 | 1572.05 | 51.85 | 1687.05 | 166.85 |
| VCC | 5 | 1711.95 | 51.85 | 1826.95 | 166.85 |
| R | 6 | 2758.85 | 237.65 | 2873.85 | 352.65 |
| LBK | 7 | 2774.25 | 1429.985 | 2889.25 | 1544.95 |
| CANL | 8 | 1549.90 | 1544.95 | 1664.90 | 1659.95 |
| CANH | 9 | 1351.45 | 1544.95 | 1466.45 | 1659.95 |
| RS | 10 | 83.50 | 1429.95 | 198.50 | 1544.95 |

PRODUCT PREVIEW

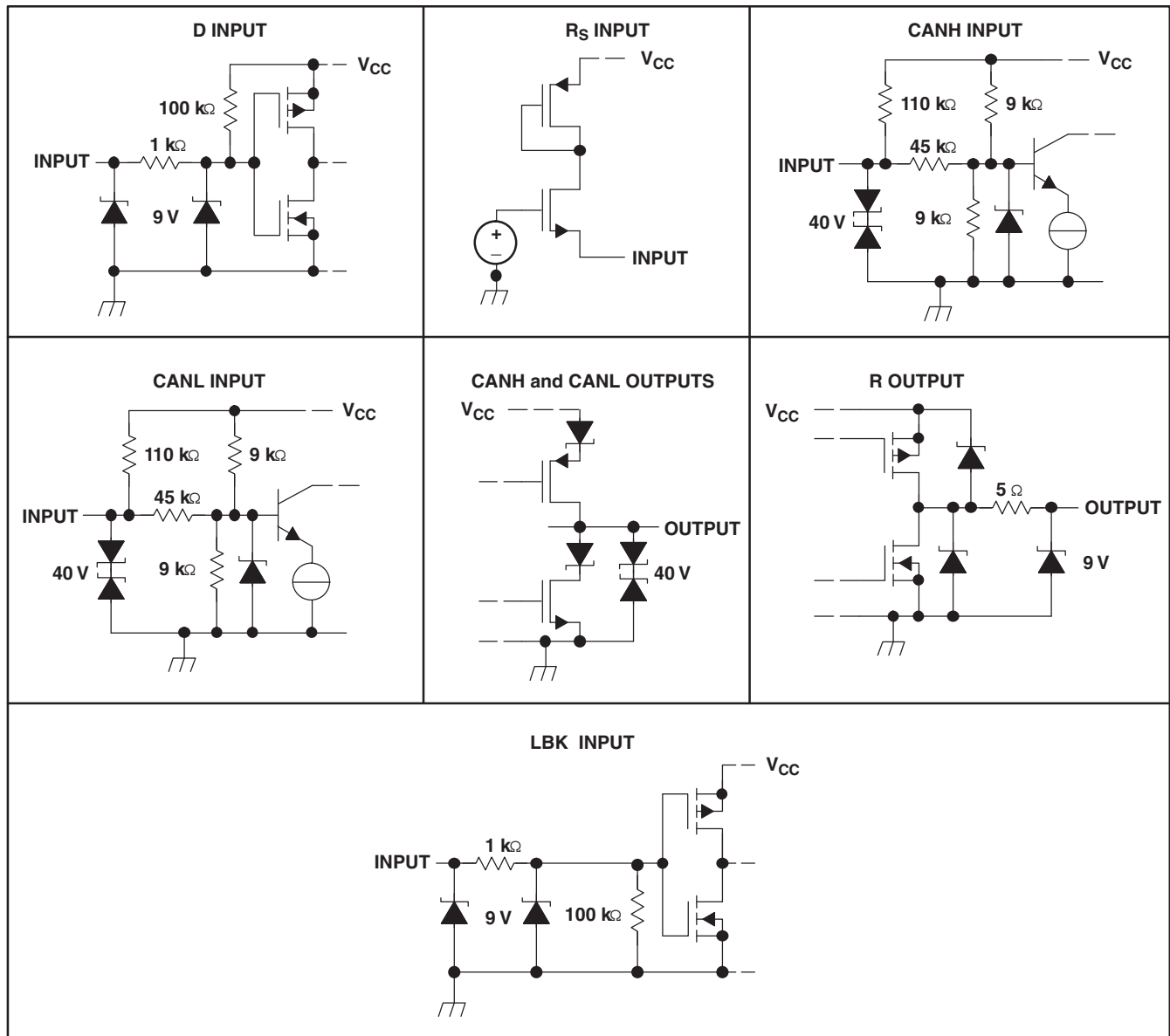


PRODUCT PREVIEW

DEVICE INFORMATION



EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



PRODUCT PREVIEW

FUNCTION TABLES⁽¹⁾

(1) H = high level, L = low level, Z = high impedance, X = irrelevant, ? = indeterminate

| DRIVER | | | | | |
|-----------|-----------|--------------------|---------|------|-----------|
| INPUTS | | | OUTPUTS | | |
| D | LBK | R _s | CANH | CANL | BUS STATE |
| X | X | $>0.75 V_{CC}$ | Z | Z | Recessive |
| L | L or open | $\leq 0.33 V_{CC}$ | H | L | Dominant |
| H or open | X | | Z | Z | Recessive |
| X | H | $\leq 0.33 V_{CC}$ | Z | Z | Recessive |

| RECEIVER | | | | |
|-----------|------------------------------------|-----------|-----------|--------|
| INPUTS | | | | OUTPUT |
| BUS STATE | $V_{ID} = V_{(CANH)} - V_{(CANL)}$ | LBK | D | R |
| Dominant | $V_{ID} \geq 0.9 V$ | L or open | X | L |
| Recessive | $V_{ID} \leq 0.5 V$ or open | L or open | H or open | H |
| ? | $0.5 V < V_{ID} < 0.9 V$ | L or open | H or open | ? |
| X | X | H | L | L |
| X | X | | H | H |

ABSOLUTE MAXIMUM RATINGS^{(1) (2)}

over operating free-air temperature range (unless otherwise noted)

| | | | VALUE | UNIT |
|-------------------------|--|---------------------|-------------|------|
| V _{CC} | Supply voltage range | | –0.3 to 7 | V |
| | Voltage range at any bus terminal (CANH or CANL) | | –36 to 36 | V |
| | Voltage input range, transient pulse (CANH and CANL) through 100 Ω (see Figure 8) | | –100 to 100 | V |
| V _I | Input voltage range (D, R, R _S , LBK) | | –0.5 to 7 | V |
| I _O | Receiver output current | | –10 to 10 | mA |
| Electrostatic discharge | Human-Body Model (HBM) ⁽³⁾ | CANH, CANL, and GND | 16 | kV |
| | | All pins | 3 | |
| | Charged-Device Mode (CDM) ⁽⁴⁾ | All pins | 1 | |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101.

RECOMMENDED OPERATING CONDITIONS

| | | | T _A = –55°C to 210°C | | UNIT |
|-------------------------------|---|----------|---------------------------------|-----|------|
| | | | MIN | MAX | |
| V _{CC} | Supply voltage | | 3 | 3.6 | V |
| | Voltage at any bus terminal (separately or common mode) | | –7 | 12 | V |
| V _{IH} | High-level input voltage | D, LBK | 2 | 5.5 | V |
| V _{IL} | Low-level input voltage | D, LBK | 0 | 0.8 | V |
| V _{ID} | Differential input voltage | | –6 | 6 | V |
| | Resistance from R _S to ground | | 0 | 100 | kΩ |
| V _{I(R_S)} | Input voltage at R _S for standby | | 0.75 V _{CC} | 5.5 | V |
| I _{OH} | High-level output current | Driver | –50 | | mA |
| | | Receiver | –10 | | |
| I _{OL} | Low-level output current | Driver | 50 | | mA |
| | | Receiver | 10 | | |
| T _J | Operating junction temperature | | 212 | | °C |
| T _A | Operating free-air temperature ⁽¹⁾ | | –55 | 210 | °C |

- (1) Maximum free-air temperature operation is allowed as long as the device maximum junction temperature is not exceeded.

DRIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS | T _A = -55°C to 125°C | | | T _A = 210°C ⁽¹⁾ | | | UNIT |
|--------------------------------|--|-----------|---|---------------------------------|-----|-----------------|---------------------------------------|------|-----------------|------|
| | | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| V _{O(D)} | Bus output voltage (dominant) | CANH | D = 0 V, R _S = 0 V, See Figure 2 and Figure 3 | 2.45 | | V _{CC} | 2.45 | | V _{CC} | V |
| | | CANL | | 0.5 | | 1.25 | 0.5 | | 1.25 | |
| V _O | Bus output voltage (recessive) | CANH | D = 3 V, R _S = 0 V, See Figure 2 and Figure 3 | 2.3 | | | 2.3 | | | V |
| | | CANL | | 2.3 | | | 2.3 | | | |
| V _{OD(D)} | Differential output voltage (Dominant) | | D = 0 V, R _S = 0 V, See Figure 2 and Figure 3 | 1.5 | 2 | 3 | 1.4 | 1.75 | 3 | V |
| | | | D = 0 V, R _S = 0 V, See Figure 3 and Figure 4 | 1.1 | 2 | 3 | 1.1 | 1.47 | 3 | |
| V _{OD} | Differential output voltage (Recessive) | | D = 3 V, R _S = 0 V, See Figure 2 and Figure 3 | -120 | | 12 | -120 | | 12 | mV |
| | | | D = 3 V, R _S = 0 V, No load | -0.5 | | 0.05 | -0.5 | | 1.2 | V |
| V _{OC(pp)} | Peak-to-peak common-mode output voltage | | See Figure 10 | 1 | | | 1 | | | V |
| I _{IH} | High-level input current | D, LBK | D = 2 V | -30 | | 30 | -30 | | 30 | μA |
| I _{IL} | Low-level input current | D, LBK | D = 0.8 V | -30 | | 30 | -30 | | 30 | μA |
| I _{OS} | Short-circuit output current | | V _{CANH} = -7 V, CANL open, See Figure 13 | -250 | | | -250 | | | mA |
| | | | V _{CANH} = 12 V, CANL open, See Figure 13 | | | | 1 | | | |
| | | | V _{CANL} = -7 V, CANH open, See Figure 13 | -1 | | | -1 | | | |
| | | | V _{CANL} = 12 V, CANH open, See Figure 13 | | | | 250 | | | |
| C _O | Output capacitance | | See receiver input capacitance | | | | | | | |
| I _{I_{RS(s)}} | R _S input current for standby | | R _S = 0.75 V _{CC} | -10 | | -10 | | | | μA |
| I _{CC} | Supply current | Standby | R _S = V _{CC} , D = V _{CC} , LBK = 0 V | 200 | | 600 | 400 | | 600 | μA |
| | | Dominant | D = 0 V, No load, LBK = 0 V, R _S = 0 V | | | | 6 | | | mA |
| | | Recessive | D = t V _{CC} , No load, LBK = 0 V, R _S = 0 V | | | | 6 | | | |

(1) Minimum and maximum parameters are characterized for operation at T_A = 210°C but may not be production tested at that temperature. Production test limits with statistical guardbands are used to ensure high temperature performance.

DRIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | T _A = -55°C to 125°C | | | T _A = 210°C ⁽¹⁾ | | | UNIT |
|--|--|---------------------------------|-----|------|---------------------------------------|------|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | |
| t _{PLH} Propagation delay time, low-to-high-level output | R _S = 0 V, See Figure 5 | | 35 | 85 | | 50 | | ns |
| | R _S with 10 kΩ to ground, See Figure 5 | | 70 | 125 | | 75 | | |
| | R _S with 100 kΩ to ground, See Figure 5 | | 500 | 870 | | 500 | | |
| t _{PHL} Propagation delay time, high-to-low-level output | R _S = 0 V, See Figure 5 | | 70 | 120 | | 70 | | ns |
| | R _S with 10 kΩ to ground, See Figure 5 | | 130 | 180 | | 130 | | |
| | R _S with 100 kΩ to ground, See Figure 5 | | 870 | 1200 | | 870 | | |
| t _{sk(p)} Pulse skew (t _{PHL} - t _{PLH}) | R _S = 0 V, See Figure 5 | | 35 | | | 9 | | ns |
| | R _S with 10 kΩ to ground, See Figure 5 | | 60 | | | 35 | | |
| | R _S with 100 kΩ to ground, See Figure 5 | | 370 | | | 475 | | |
| t _r Differential output signal rise time | R _S = 0 V, See Figure 5 | | 20 | 70 | 20 | 75 | | ns |
| t _f Differential output signal fall time | | | 18 | 70 | 20 | 75 | | |
| t _r Differential output signal rise time | R _S with 10 kΩ to ground, See Figure 5 | | 30 | 135 | 30 | 140 | | ns |
| t _f Differential output signal fall time | | | 30 | 135 | 30 | 140 | | |
| t _r Differential output signal rise time | R _S with 100 kΩ to ground, See Figure 5 | | 250 | 1400 | 250 | 1400 | | ns |
| t _f Differential output signal fall time | | | 350 | 1400 | 350 | 1400 | | |
| t _{en(s)} Enable time from standby to dominant | See Figure 9 | | 0.6 | 1.5 | | 0.6 | 1.5 | μs |

- (1) Minimum and maximum parameters are characterized for operation at T_A = 210°C but may not be production tested at that temperature. Production test limits with statistical guardbands are used to ensure high temperature performance.

Table 1. THERMAL CHARACTERISTICS

| PARAMETERS | | TEST CONDITIONS | MAX | UNIT |
|---|--|--|------|------|
| θ _{JA} Junction-to-ambient thermal resistance ⁽¹⁾ | | Low-K ⁽²⁾ board, no air flow | 83.4 | °C/W |
| | | High-K ⁽³⁾ board, no air flow | 64.9 | |
| θ _{JB} Junction-to-board thermal resistance | | High-K ⁽³⁾ board, no air flow | 27.9 | °C/W |
| θ _{JC} Junction-to-case thermal resistance | | | 6.49 | °C/W |
| P _(AVG) Average power dissipation | | R _L = 60 Ω, R _S = 0 V, input to D a 1-MHz 50% duty cycle square wave, V _{CC} = 3.3 V, T _A = 25°C | 114 | mW |

- (1) See TI literature number [SZZA003](#) for an explanation of this parameter.
 (2) JESD51-3 low effective thermal conductivity test board for leaded surface-mount packages.
 (3) JESD51-7 high effective thermal conductivity test board for leaded surface-mount packages.

RECEIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | $T_A = -55^\circ\text{C to } 125^\circ\text{C}$ | | | $T_A = 210^\circ\text{C}^{(1)}$ | | | UNIT | |
|-----------|--|--|---|--------|---------------------------------|--------|---------------|------------|---------------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | | |
| V_{IT+} | Positive-going input threshold voltage | 620 900 | | | 600 900 | | | mV | |
| V_{IT-} | Negative-going input threshold voltage | 500 715 | | | 500 725 | | | mV | |
| V_{hys} | Hysteresis voltage ($V_{IT+} - V_{IT-}$) | 100 | | | 140 | | | mV | |
| V_{OH} | High-level output voltage | $I_O = -4\text{ mA}$, See Figure 7 | | | 2.4 | | | V | |
| V_{OL} | Low-level output voltage | $I_O = 4\text{ mA}$, See Figure 7 | | | 0.4 | | | V | |
| I_I | Bus input current | CANH or CANL = 12 V | 140 500 | | 140 500 | | μA | | |
| | | CANH or CANL = 12 V, $V_{CC} = 0\text{ V}$ | 200 600 | | 200 800 | | | | |
| | | CANH or CANL = -7 V | -610 -150 | | -610 -150 | | | | |
| | | CANH or CANL = -7 V, $V_{CC} = 0\text{ V}$ | -450 -130 | | -450 -130 | | | | |
| C_I | Input capacitance (CANH or CANL) | Pin to ground, $V_I = 0.4 \sin(4E6\pi t) + 0.5\text{ V}$, $D = 3\text{ V}$, $LBK = 0\text{ V}$ | | 45 | | 55 | | pF | |
| C_{ID} | Differential input capacitance | Pin to pin, $V_I = 0.4 \sin(4E6\pi t) + 0.5\text{ V}$, $D = 3\text{ V}$, $LBK = 0\text{ V}$ | | 15 | | 15 | | pF | |
| R_{ID} | Differential input resistance | $D = 3\text{ V}$, $LBK = 0\text{ V}$ | | 40 110 | | 40 110 | | k Ω | |
| R_{IN} | Input resistance (CANH or CANL) | $D = 3\text{ V}$, $LBK = 0\text{ V}$ | | 20 51 | | 18 51 | | k Ω | |
| I_{CC} | Supply current | Standby | $R_S = V_{CC}$, $D = V_{CC}$, $LBK = 0\text{ V}$ | | 200 600 | | 400 600 | | μA |
| | | Dominant | $D = 0\text{ V}$, No load, $R_S = 0\text{ V}$, $LBK = 0\text{ V}$ | | 6 | | 6 | | mA |
| | | Recessive | $D = V_{CC}$, No load, $R_S = 0\text{ V}$, $LBK = 0\text{ V}$ | | 6 | | 6 | | |

(1) Minimum and maximum parameters are characterized for operation at $T_A = 210^\circ\text{C}$ but may not be production tested at that temperature. Production test limits with statistical guardbands are used to ensure high temperature performance.

RECEIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | T _A = -55°C to 125°C | | | T _A = 210°C ⁽¹⁾ | | | UNIT |
|--------------------|---|-----------------|---------------------------------|-----|-----|---------------------------------------|-----|-----|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| t _{PLH} | Propagation delay time, low-to-high-level output | See Figure 7 | 35 | 60 | | 50 | 60 | ns | |
| t _{PHL} | Propagation delay time, high-to-low-level output | | 35 | 60 | | 45 | 60 | ns | |
| t _{sk(p)} | Pulse skew (t _{PHL} - t _{PLH}) | | 7 | | | 5 | | ns | |
| t _r | Output signal rise time | | 2 | 6.5 | | 6.5 | 8 | ns | |
| t _f | Output signal fall time | | 2 | 6.5 | | 6.5 | 9 | ns | |

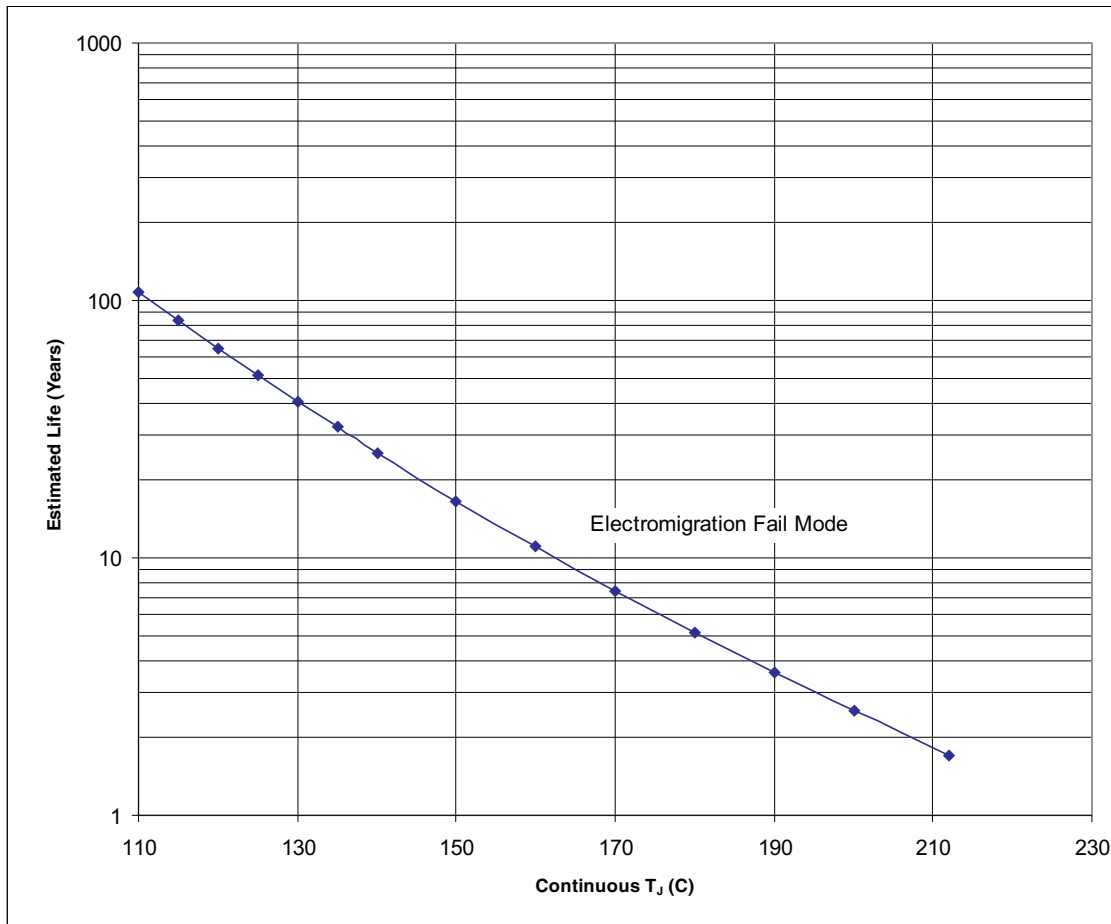
- (1) Minimum and maximum parameters are characterized for operation at T_A = 210°C but may not be production tested at that temperature. Production test limits with statistical guardbands are used to ensure high temperature performance.

DEVICE SWITCHING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | T _A = -55°C to 125°C | | | T _A = 210°C ⁽¹⁾ | | | UNIT |
|----------------------|--|---|---------------------------------|------|-----|---------------------------------------|------|-----|------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| t _(LBK) | Loopback delay, driver input to receiver output | See Figure 12 | 7.5 | 15 | | 12 | 15 | ns | |
| t _(loop1) | Total loop delay, driver input to receiver output, recessive to dominant | R _S = 0 V, See Figure 11 | 70 | 135 | | 90 | 135 | ns | |
| | | R _S with 10 kΩ to ground, See Figure 11 | 105 | 190 | | 115 | 190 | | |
| | | R _S with 100 kΩ to ground, See Figure 11 | 535 | 1000 | | 430 | 1000 | | |
| t _(loop2) | Total loop delay, driver input to receiver output, dominant to recessive | R _S = 0 V, See Figure 11 | 70 | 135 | | 98 | 135 | ns | |
| | | R _S with 10 kΩ to ground, See Figure 11 | 105 | 190 | | 150 | 190 | | |
| | | R _S with 100 kΩ to ground, See Figure 11 | 535 | 1100 | | 880 | 1200 | | |

- (1) Minimum and maximum parameters are characterized for operation at T_A = 210°C but may not be production tested at that temperature. Production test limits with statistical guardbands are used to ensure high temperature performance.



- A. See data sheet for absolute maximum and minimum recommended operating conditions.
- B. Silicon operating life design goal is 10 years at 105°C junction temperature (does not include package interconnect life).

Figure 1. SN65HVD233SJD / SN65HVD233SKGDA Operating Life Derating Chart

PRODUCT PREVIEW

PARAMETER MEASUREMENT INFORMATION

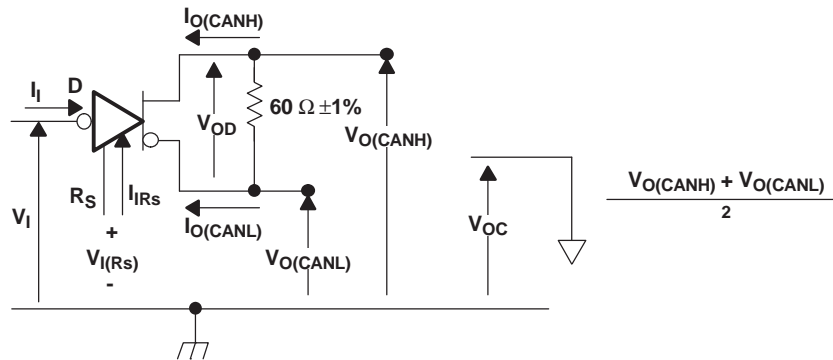


Figure 2. Driver Voltage, Current, and Test Definition

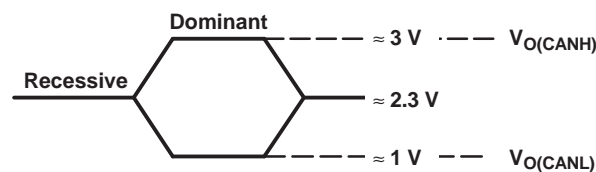


Figure 3. Bus Logic State Voltage Definitions

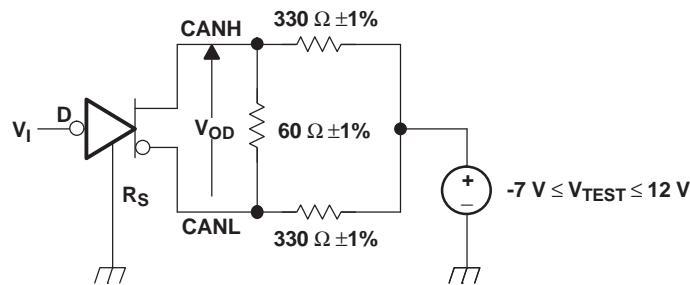
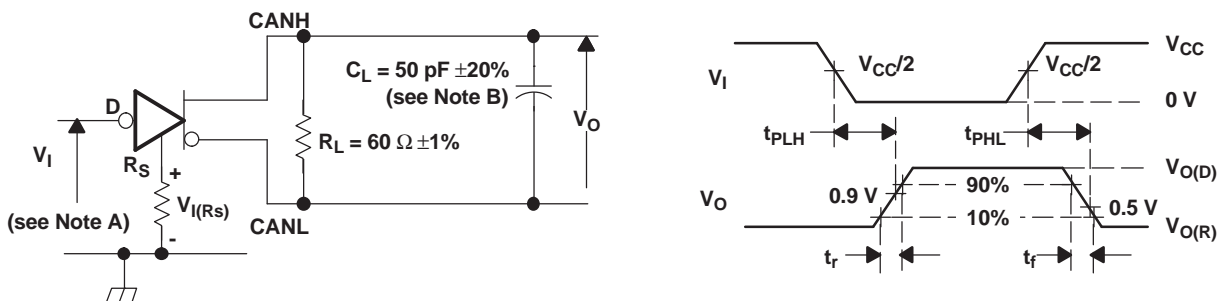


Figure 4. Driver V_{OD}



- A. The input pulse is supplied by a generator having the following characteristics: Pulse repetition rate (PRR) ≤ 125 kHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
- B. C_L includes fixture and instrumentation capacitance.

Figure 5. Driver Test Circuit and Voltage Waveforms

PRODUCT PREVIEW

PARAMETER MEASUREMENT INFORMATION (continued)

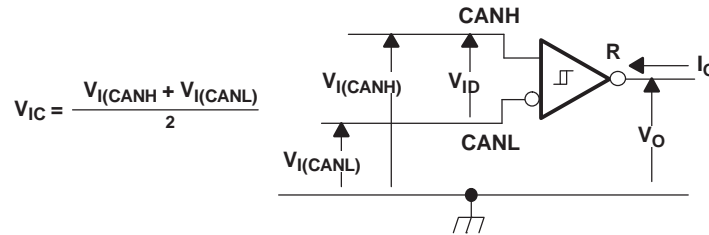
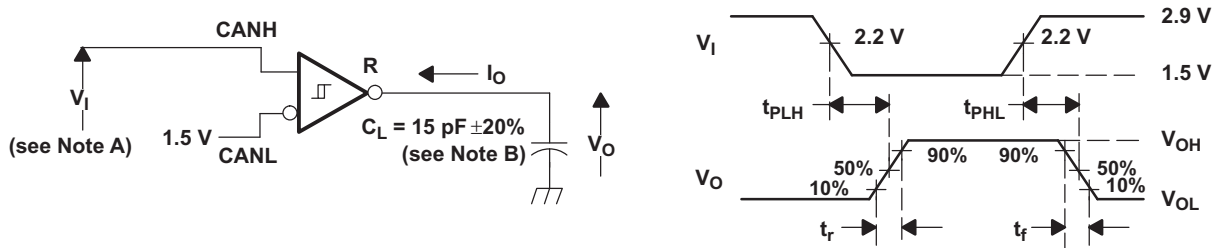


Figure 6. Receiver Voltage and Current Definitions

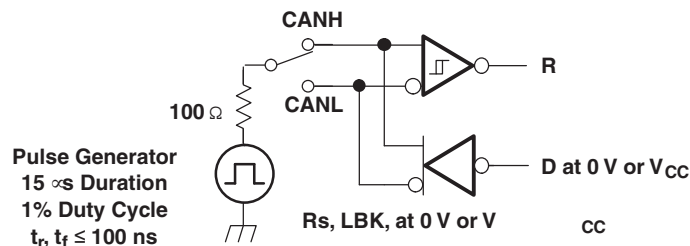


- A. The input pulse is supplied by a generator having the following characteristics: Pulse repetition rate (PRR) ≤ 125 kHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
- B. C_L includes fixture and instrumentation capacitance.

Figure 7. Receiver Test Circuit and Voltage Waveforms

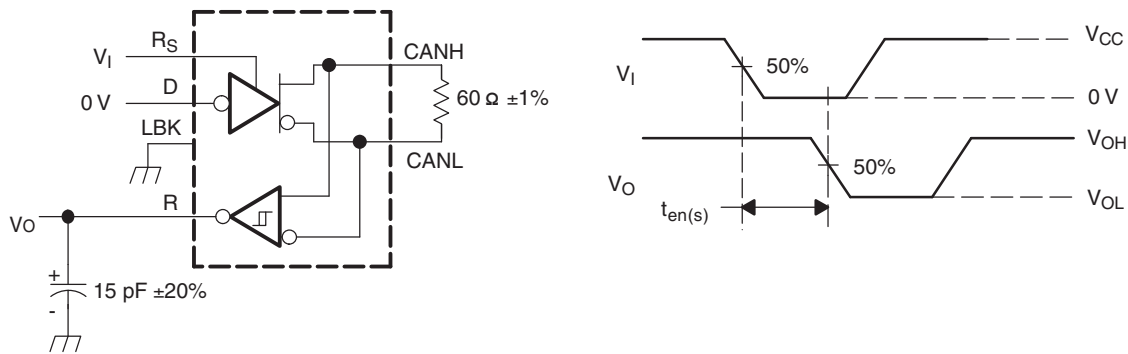
Table 2. Differential Input Voltage Threshold Test

| INPUT | | OUTPUT | | MEASURED |
|------------|------------|--------|----------|------------|
| V_{CANH} | V_{CANL} | R | | $ V_{ID} $ |
| -6.1 V | -7 V | L | V_{OL} | 900 mV |
| 12 V | 11.1 V | L | | 900 mV |
| -1 V | -7 V | L | | 6 V |
| 12 V | 6 V | L | | 6 V |
| -6.5 V | -7 V | H | V_{OH} | 500 mV |
| 12 V | 11.5 V | H | | 500 mV |
| -7 V | -1 V | H | | 6 V |
| 6 V | 12 V | H | | 6 V |
| Open | Open | H | | X |



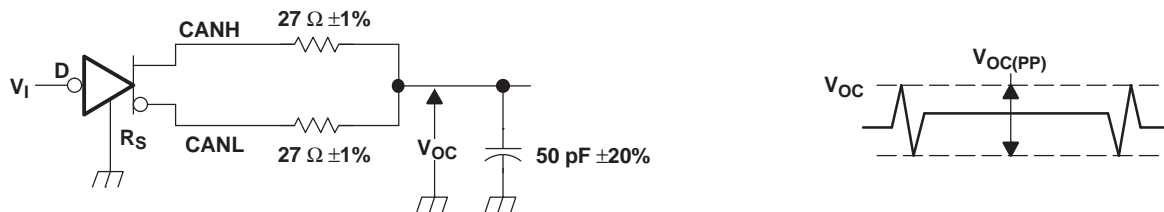
NOTE: This test is conducted to test survivability only. Data stability at the R output is not specified.

Figure 8. Test Circuit, Transient Over Voltage Test



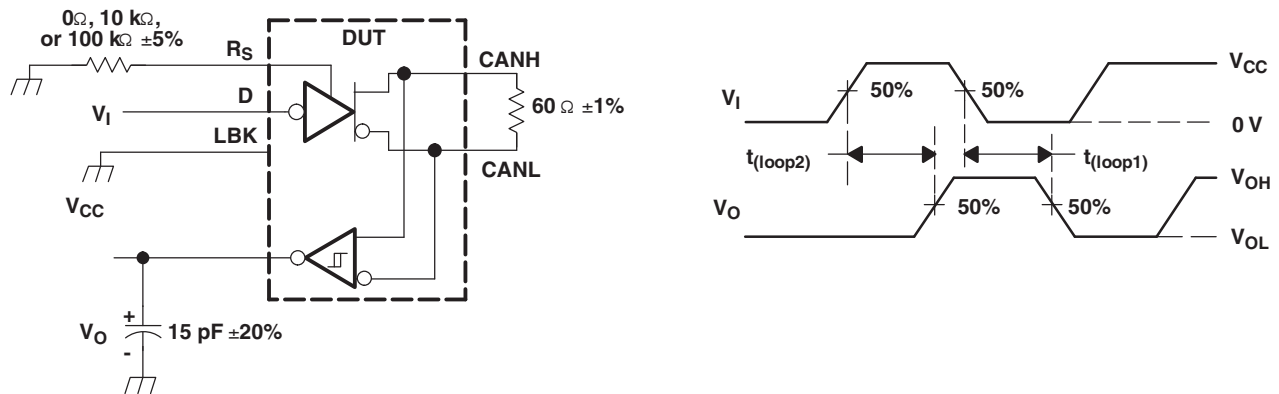
NOTE: All V_I input pulses are supplied by a generator having the following characteristics:
 t_r or $t_f \leq 6$ ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.

Figure 9. $t_{en(s)}$ Test Circuit and Voltage Waveforms



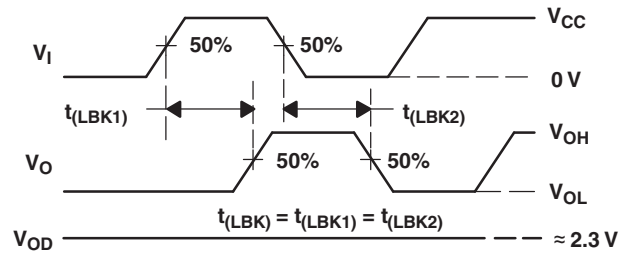
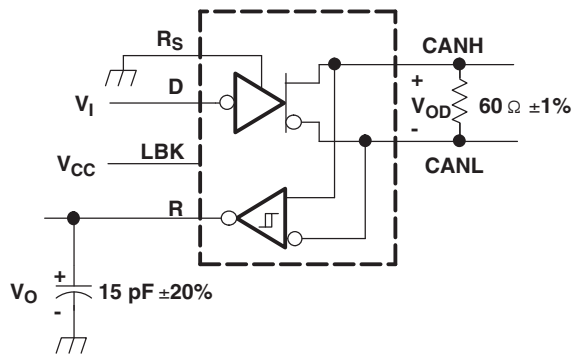
NOTE: All V_I input pulses are supplied by a generator having the following characteristics:
 t_r or $t_f \leq 6$ ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.

Figure 10. $V_{OC(pp)}$ Test Circuit and Voltage Waveforms



NOTE: All V_I input pulses are supplied by a generator having the following characteristics:
 t_r or $t_f \leq 6$ ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.

Figure 11. $t_{(loop)}$ Test Circuit and Voltage Waveforms



NOTE: All V_I input pulses are supplied by a generator having the following characteristics:
 t_r or $t_f \leq 6$ ns, pulse repetition rate (PRR) = 125 kHz, 50% duty cycle.

Figure 12. $t_{(LBK)}$ Test Circuit and Voltage Waveforms

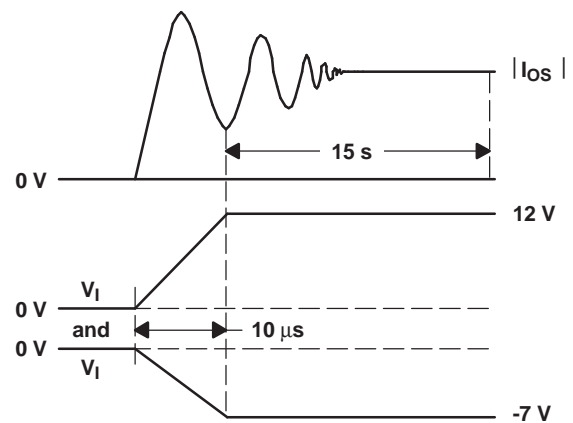
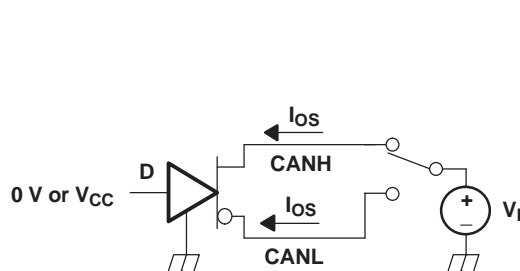
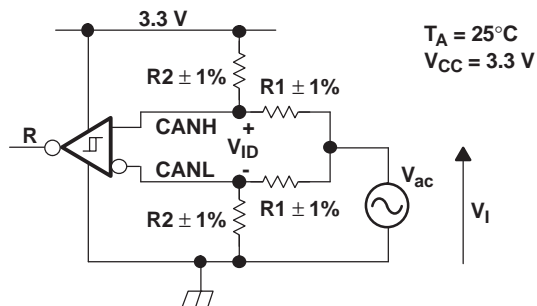


Figure 13. I_{OS} Test Circuit and Waveforms

PRODUCT PREVIEW



The R Output State Does Not Change During Application of the Input Waveform.

| V_{ID} | R1 | R2 |
|----------|-------------|--------------|
| 500 mV | 50 Ω | 280 Ω |
| 900 mV | 50 Ω | 130 Ω |



NOTE: All input pulses are supplied by a generator with $f \leq 1.5$ MHz.

Figure 14. Common-Mode Voltage Rejection

TYPICAL CHARACTERISTICS

RECESSIVE-TO-DOMINANT LOOP TIME
vs
FREE-AIR TEMPERATURE

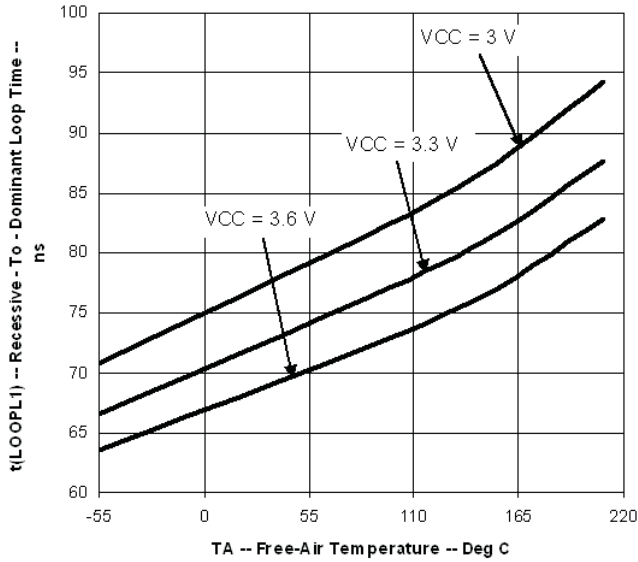


Figure 15.

DOMINANT-TO-RECESSIVE LOOP TIME
vs
FREE-AIR TEMPERATURE

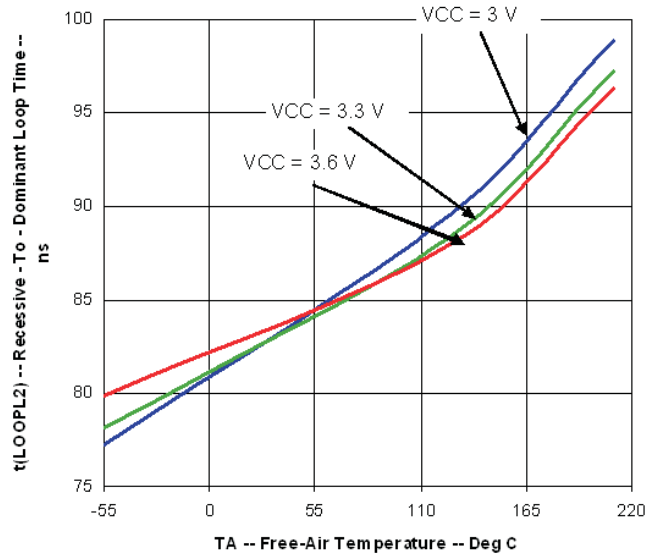


Figure 16.

SUPPLY CURRENT
vs
FREQUENCY

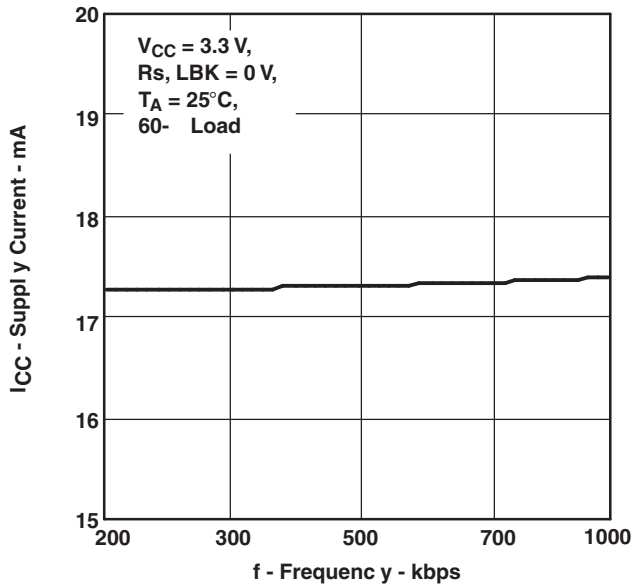


Figure 17.

DRIVER LOW-LEVEL OUTPUT CURRENT
vs
LOW-LEVEL OUTPUT VOLTAGE

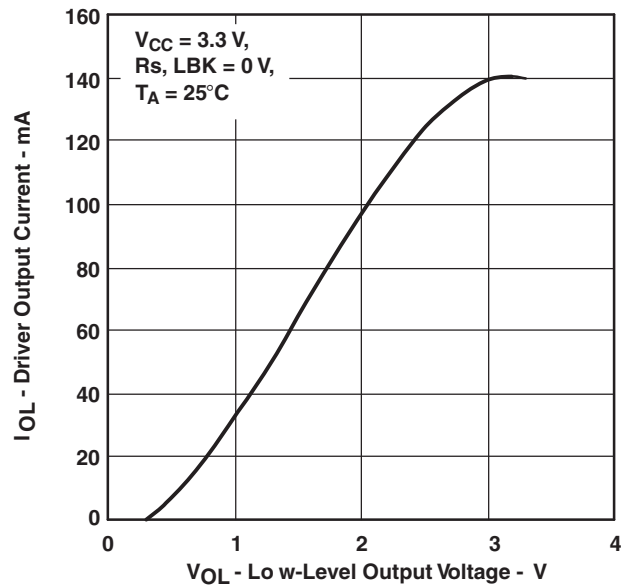


Figure 18.

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS (continued)

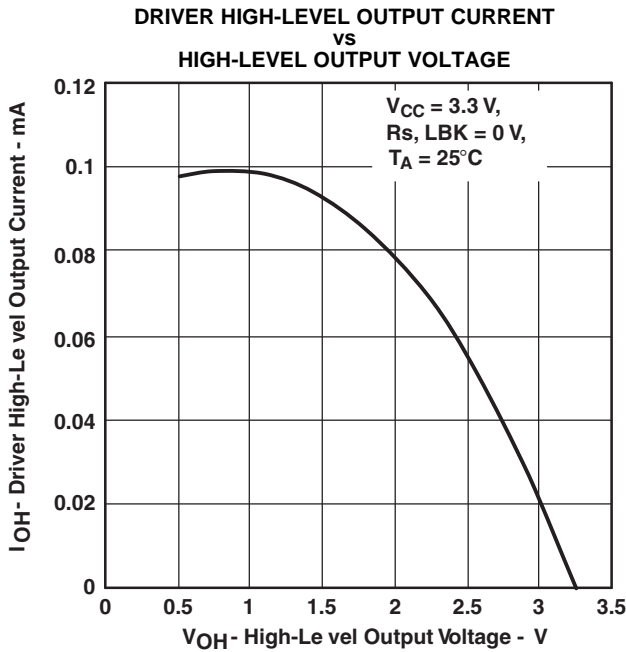


Figure 19.

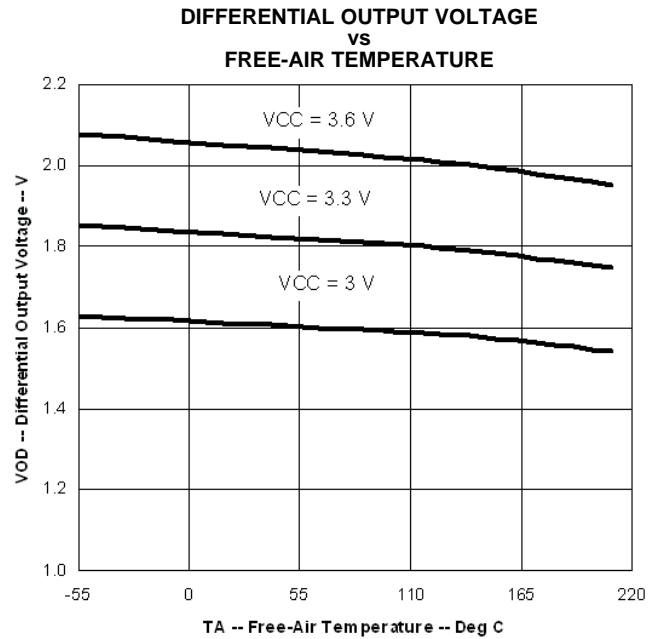


Figure 20.

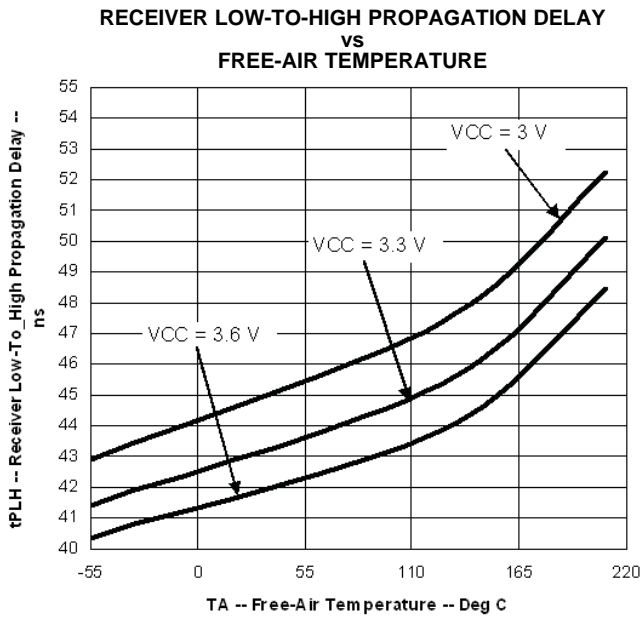


Figure 21.

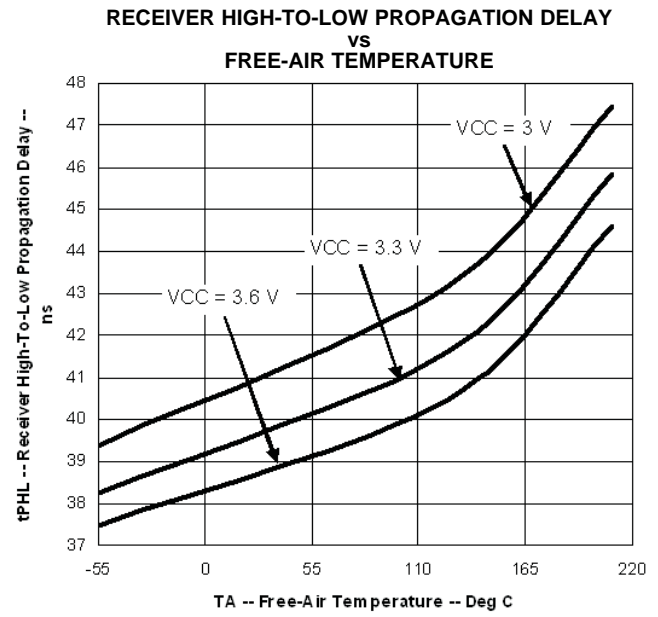


Figure 22.

PRODUCT PREVIEW

TYPICAL CHARACTERISTICS (continued)

DRIVER LOW-TO-HIGH PROPAGATION DELAY
vs
FREE-AIR TEMPERATURE

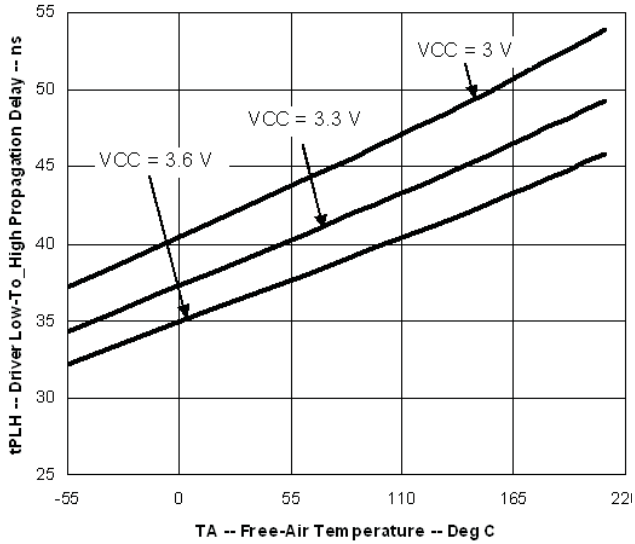


Figure 23.

DRIVER HIGH-TO-LOW PROPAGATION DELAY
vs
FREE-AIR TEMPERATURE

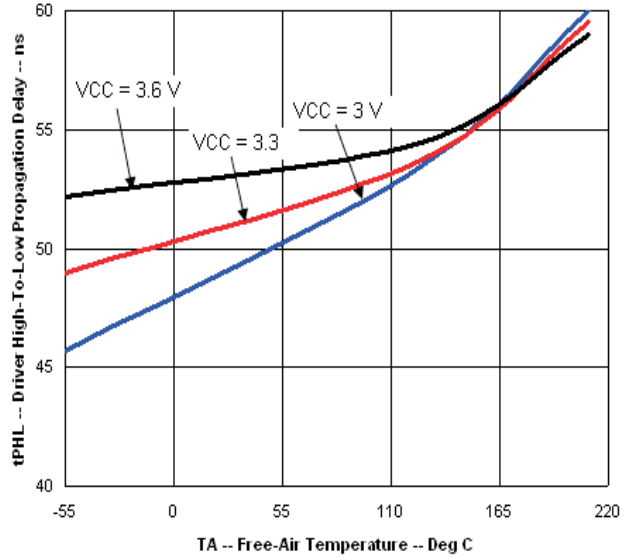


Figure 24.

DRIVER OUTPUT CURRENT
vs
SUPPLY VOLTAGE

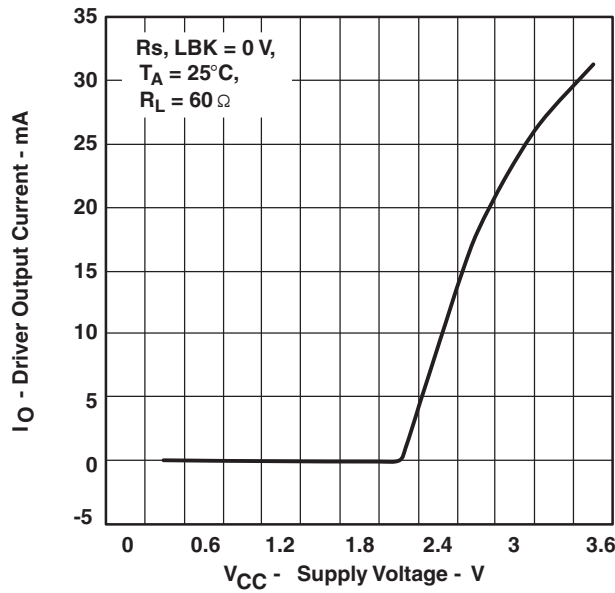


Figure 25.

PRODUCT PREVIEW

APPLICATION INFORMATION

Diagnostic Loopback

The loopback (LBK) function of the SN65HVD233 is enabled with a high-level input to pin 5. This forces the driver into a recessive state and redirects the data (D) input at pin 1 to the received-data (R) output at pin 4. This allows the host controller to input and read back a bit sequence to perform diagnostic routines without disturbing the CAN bus. A typical CAN bus application is displayed in Figure 26.

If the LBK pin is not used, it may be tied to ground (GND). However, it is pulled low internally (defaults to a low-level input) and may be left open if not in use.

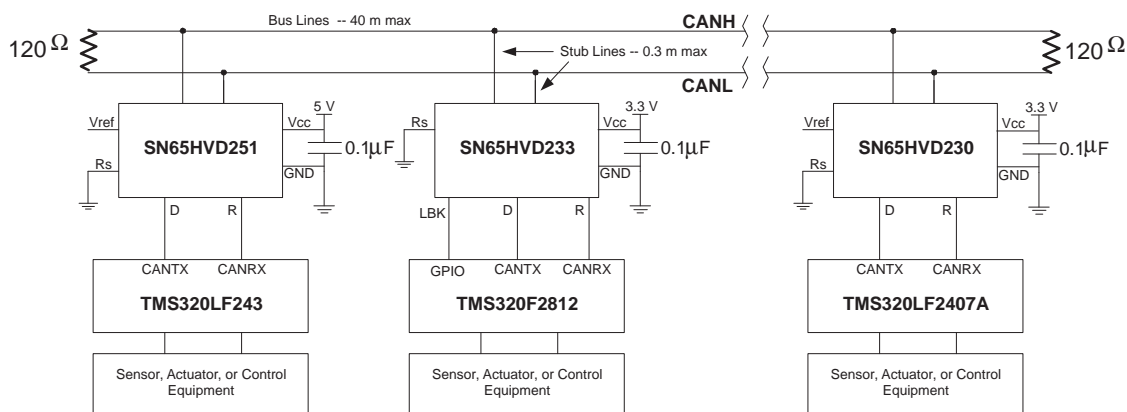


Figure 26. Typical SN65HVD233 Application

ISO 11898 Compliance of SN65HVD230 Family of 3.3-V CAN Transceivers

Introduction

Many users value the low power consumption of operating CAN transceivers from a 3.3-V supply. However, some are concerned about the interoperability with 5-V supplied transceivers on the same bus. This section analyzes this situation to address those concerns.

Differential Signal

CAN is a differential bus where complementary signals are sent over two wires, and the voltage difference between the two wires defines the logical state of the bus. The differential CAN receiver monitors this voltage difference and outputs the bus state with a single-ended output signal.

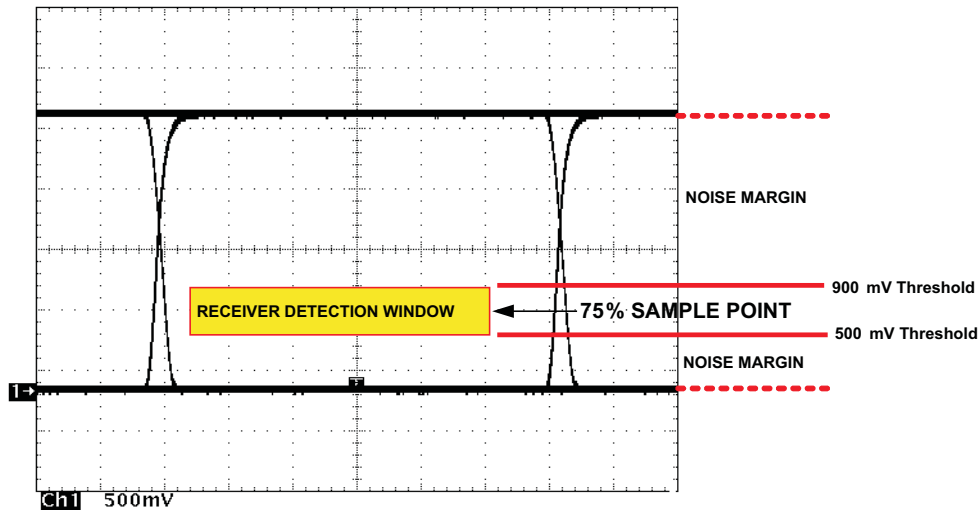


Figure 27. Typical SN65HVD230 Differential Output Voltage Waveform

The CAN driver creates the difference voltage between CANH and CANL in the dominant state. The dominant differential output of the SN65HVD230 is greater than 1.5 V and less than 3 V across a 60-Ω load. The minimum required by ISO 11898 is 1.5 V and the maximum is 3 V. These are the same limiting values for 5-V supplied CAN transceivers. The bus termination resistors drive the recessive bus state and not the CAN driver.

A CAN receiver is required to output a recessive state with less than 500 mV and a dominant state with more than 900-mV difference voltage on its bus inputs. The CAN receiver must do this with common-mode input voltages from –2 V to 7 V. The SN65HVD230 family receivers meet these same input specifications as 5-V supplied receivers.

Common-Mode Signal

A common-mode signal is an average voltage of the two signal wires that the differential receiver rejects. The common-mode signal comes from the CAN driver, ground noise, and coupled bus noise. Obviously, the supply voltage of the CAN transceiver has nothing to do with noise. The SN65HVD230 family driver lowers the common-mode output in a dominant bit by a couple hundred millivolts from that of most 5-V drivers. While this does not fully comply with ISO 11898, this small variation in the driver common-mode output is rejected by differential receivers and does not affect data, signal noise margins, or error rates.

Interoperability of 3.3-V CAN in 5-V CAN Systems

The 3.3-V–supplied SN65HVD23x family of CAN transceivers are electrically interchangeable with 5-V CAN transceivers. The differential output is the same. The recessive common-mode output is the same. The dominant common-mode output voltage is a couple hundred millivolts lower than 5-V–supplied drivers, while the receivers exhibit identical specifications as 5-V devices.

Electrical interoperability does not assure interchangeability however. Most implementers of CAN buses recognize that ISO 11898 does not sufficiently specify the electrical layer and that strict standard compliance alone does not ensure interchangeability. This comes only with thorough equipment testing.

Bus Cable

ISO 11898 specifies a maximum bus length of 40 m and maximum stub length of 0.3 m with a maximum of 30 nodes. However, with careful design, users can have longer cables, longer stub lengths, and many more nodes to a bus. A large number of nodes requires a transceiver with high input impedance, such as the SN65HVD233.

The standard specifies the interconnect to be a single twisted-pair cable (shielded or unshielded) with 120-Ω characteristic impedance (Z_0). Resistors equal to the characteristic impedance of the line terminate both ends of the cable to prevent signal reflections. Unterminated drop lines (stubs) connecting nodes to the bus should be kept as short as possible to minimize signal reflections.

Slope Control

The rise and fall slope of the SN65HVD233 driver output can be adjusted by connecting a resistor from R_s (pin 8) to ground (GND), or to a low-level input voltage (see Figure 28).

The slope of the driver output signal is proportional to the pin's output current. This slope control is implemented with an external resistor value of 10 kΩ to achieve a $\approx 15\text{-V}/\mu\text{s}$ slew rate, and up to 100 kΩ to achieve a $\approx 2.0\text{-V}/\mu\text{s}$ slew rate (see Figure 29). Typical driver output waveforms with slope control are displayed in Figure 30.

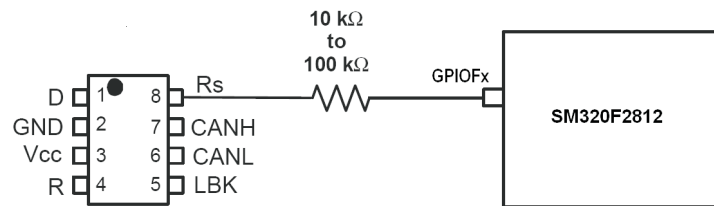


Figure 28. Slope Control/Standby Connection to DSP

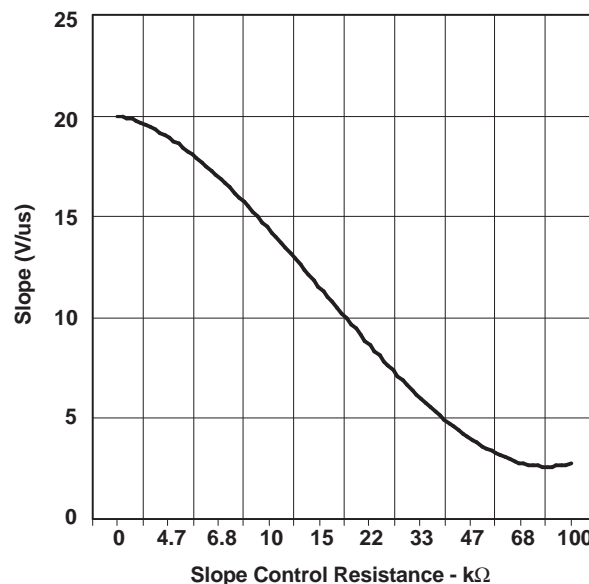


Figure 29. SN65HVD233 Driver Output Signal Slope vs Slope Control Resistance Value

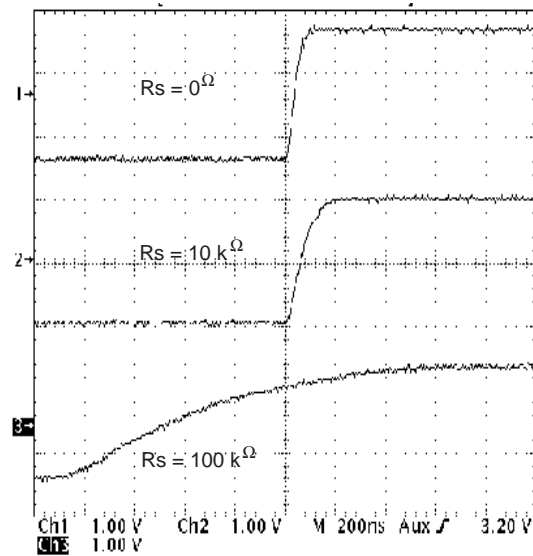


Figure 30. Typical SN65HVD233 250-kbps Output Pulse Waveforms With Slope Control

STANDBY

If a high-level input ($>0.75 V_{CC}$) is applied to R_s , the circuit enters a low-current, *listen-only* standby mode, during which the driver is switched off and the receiver remains active. The local controller can reverse this low-power standby mode when the rising edge of a dominant state (bus differential voltage >900 mV typical) occurs on the bus.

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN65HVD233DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN65HVD234DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN65HVD235DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN65HVD233DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| SN65HVD234DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| SN65HVD235DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |

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